

10Amp. Ultrafast Plastic Rectifiers

MUR1060F2

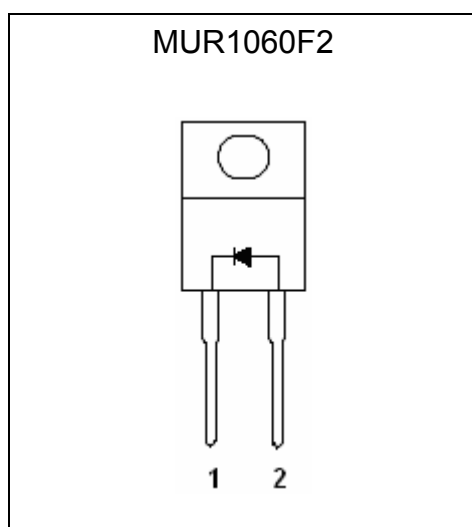
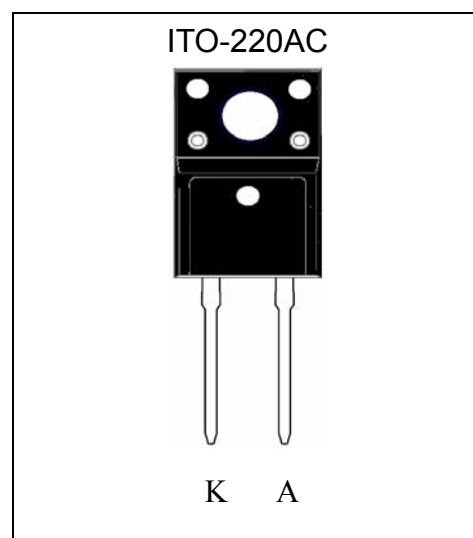
$I_{F(AV)}$	10A
V_{RRM}	600V
I_{FSM}	120A
trr	60ns
T_j	175°C
$V_{F(MAX)}$	1.5V

Features

- 175°C operating junction temperature
- Glass passivated chip junction
- Low leakage current
- Low switching loss, high efficiency
- High forward surge capability
- Insulating package, insulating voltage=2500V AC
- High temperature soldering guaranteed : 260°C/40s, 0.25”(6.35mm) from case
- Pb-free lead plating package

Mechanical Data

- Case: ITO-220AC molded plastic
- Mounting Position: Any
- Weight: 1.85 grams, 0.065 ounce approximately
- Terminals: Pure tin plated, solderable per J-STD-002 and JESD22-B102
- Epoxy: UL 94V-0 rate flame retardant
- Mounting torque: 10 in.-lb. maximum

Equivalent Circuit

Outline


**Maximum Ratings and Electrical Characteristics**

(Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.)

Parameter	Symbol	Min.	Typ.	Max.	Units
Maximum Recurrent peak reverse voltage	V_{RRM}			600	V
Maximum RMS voltage	V_{RMS}			420	V
Maximum DC blocking voltage	V_{DC}			600	V
Maximum instantaneous forward voltage at $I_F=10A$	V_F		1.25	1.5	V
Maximum Average forward rectified current @ $T_C=100^\circ C$	$I_{F(AV)}$			10	A
Non-repetitive peak forward surge current @ 8.3ms single half sine wave superimposed on rated load (JEDEC method)	I_{FSM}			120	A
Maximum instantaneous reverse current at	I_R	$V_R=600V, T_C=25^\circ C$		10	μA
		$V_R=600V, T_C=125^\circ C$		100	
Maximum reverse recovery time	t_{rr}	$I_F=1A, V_R=30V, dI_F/dt=100A/\mu s$		60	ns
Typical junction capacitance @ $f=1MHz$ and applied 4V reverse voltage	C_J		80		pF
Isolation voltage from terminal to heatsink, $t=1$ minute	V_{AC}	2500			V
Storage temperature range	T_{stg}	-65		+175	$^\circ C$
Operating junction temperature range	T_J	-65		+175	$^\circ C$

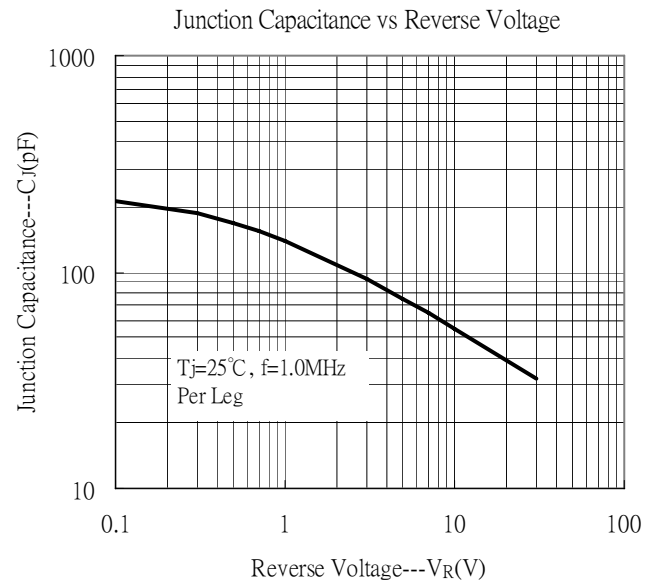
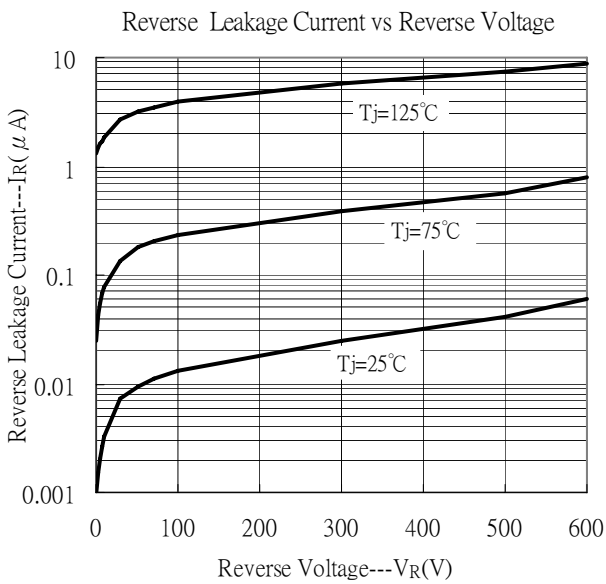
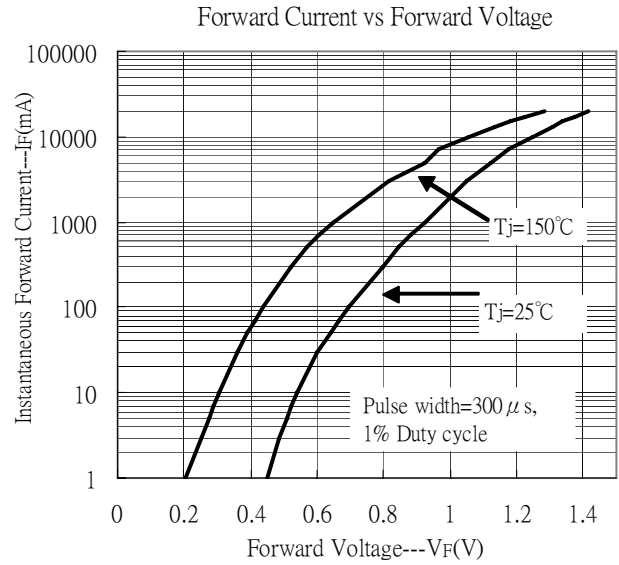
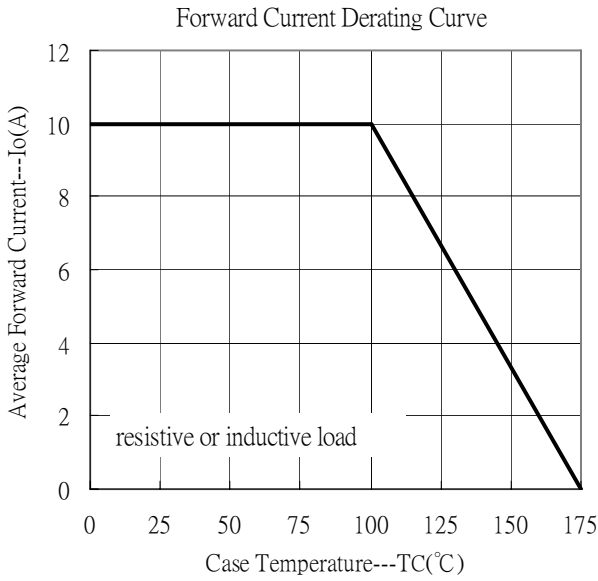
Thermal Data

Parameter	Symbol	Value	Unit
Maximum Thermal Resistance, Junction-to-case	$R_{th,j-c}$	4	$^\circ C/W$
Maximum Thermal Resistance, Junction-to-ambient	$R_{th,j-a}$	60	$^\circ C/W$

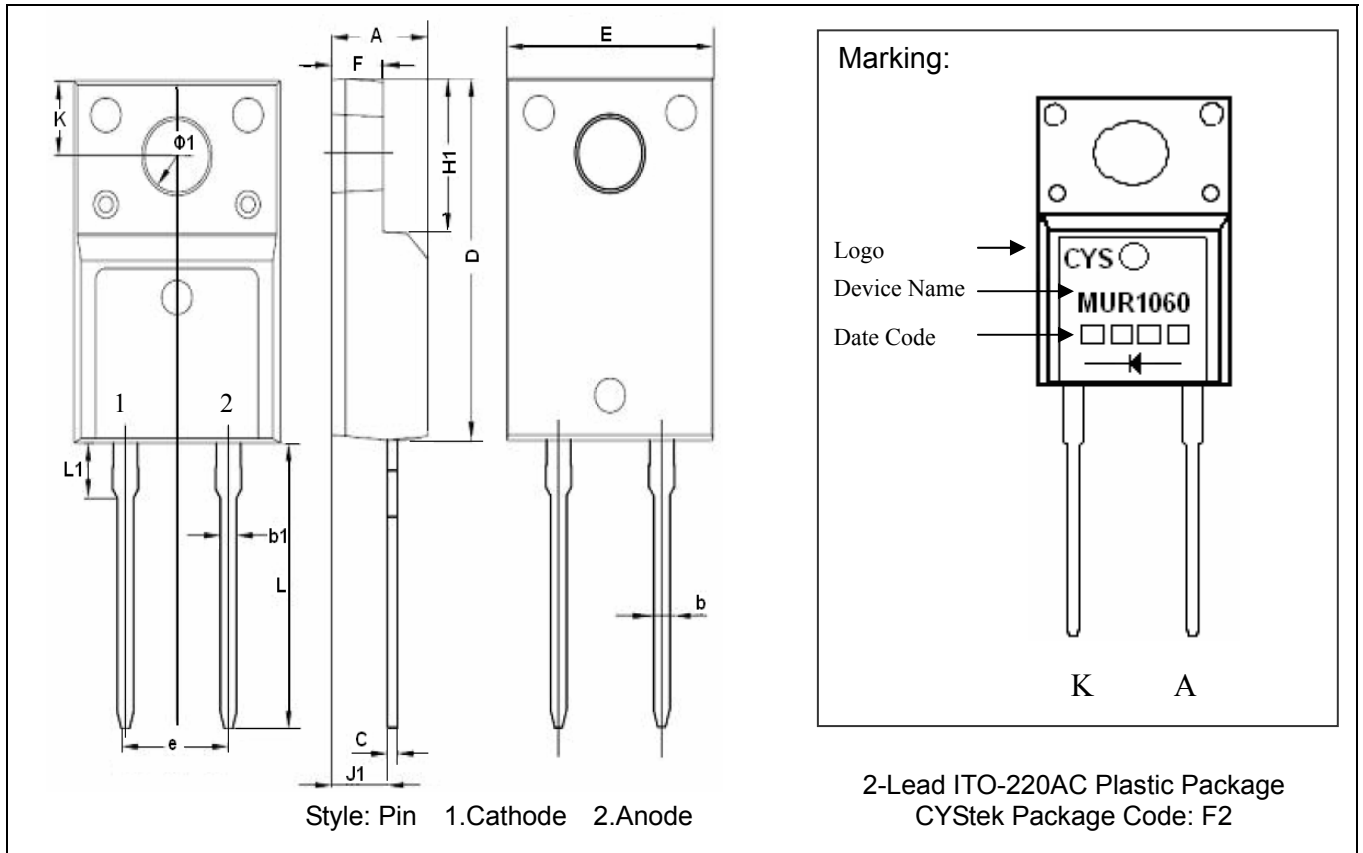
Ordering Information

Device	Package	Shipping
MUR1060F2	ITO-220AC (RoHS compliant package)	50 pcs / Tube, 40 Tubes/Box

Characteristic Curves



ITO-220AC Dimension



*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.178	0.194	4.53	4.93	H1	0.256	0.272	6.50	6.90
b	0.028	0.036	0.71	0.91	J1	0.101	0.117	2.56	2.96
C	0.014	0.021	0.36	0.53	L	0.487	0.503	12.37	12.77
D	0.617	0.633	15.67	16.07	Φ1	0.117	0.133	2.98	3.38
E	0.274	0.408	6.96	10.36	b1	0.045	0.055	1.15	1.39
F	0.092	0.108	2.34	2.74	L1	0.088	0.104	2.23	2.63
e	*0.200		*5.08		K	0.122	0.138	3.10	3.50

Notes: 1.Controlling dimension: millimeters.
 2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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